

N-Channel General Purpose Amplifier

This device is a low level audio amplifier and switching transistors, and can be used for analog switching applications. Sourced from Process 55.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{DG}	Drain-Gate Voltage	25	V
V_{GS}	Gate-Source Voltage	- 25	V
I_{GF}	Forward Gate Current	10	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

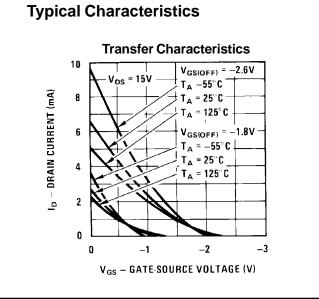
Symbol	Characteristic Max		Units	
		2N5457-5459	*MMBF5457-5459	
PD	Total Device Dissipation	625	350	mW
	Derate above 25°C	5.0	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

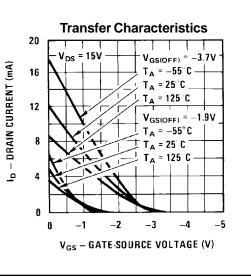
*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

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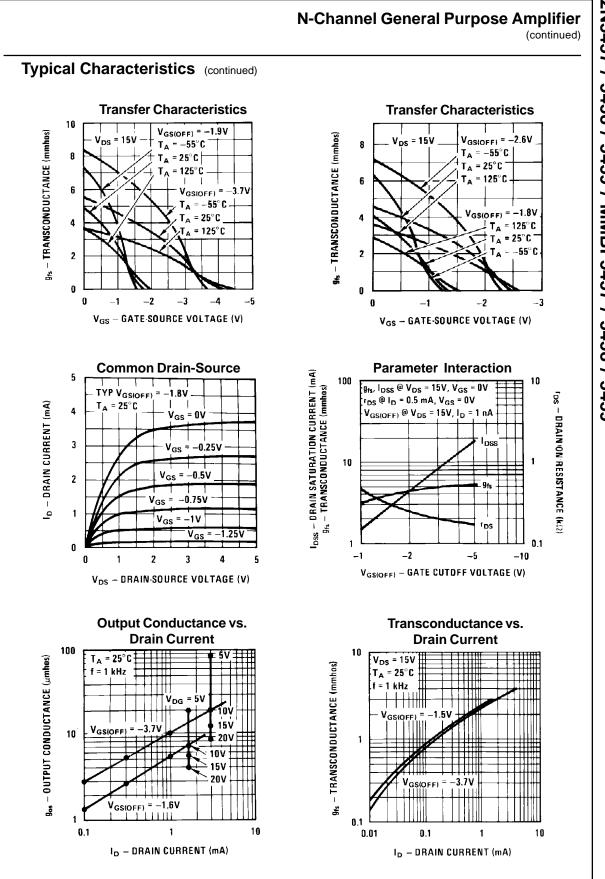
N-Channel General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
OFF CHA	RACTERISTICS					
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$I_G = 10 \ \mu A, \ V_{DS} = 0$	- 25			V
I _{GSS}	Gate Reverse Current	$V_{GS} = -15 V, V_{DS} = 0$ $V_{GS} = -15 V, V_{DS} = 0, T_A = 100^{\circ}0$	2		- 1.0 - 200	nA nA
V _{GS(off)}	Gate-Source Cutoff Voltage	V _{DS} = 15 V, I _D = 10 nA 5457 5458 5459	- 0.5 - 1.0 - 2.0		- 6.0 - 7.0 - 8.0	V V V
V _{GS}	Gate-Source Voltage	$\begin{array}{ll} V_{DS} = 15 \ V, \ I_D = 100 \ \mu A & \ \mbox{5457} \\ V_{DS} = 15 \ V, \ I_D = 200 \ \mu A & \ \mbox{5458} \\ V_{DS} = 15 \ V, \ I_D = 400 \ \mu A & \ \mbox{5459} \end{array}$		- 2.5 - 3.5 - 4.5		V V V
I _{DSS}	Zero-Gate Voltage Drain Current*	V _{DS} = 15 V, V _{GS} = 0 5457 5458 5459	1.0 2.0 4.0	3.0 6.0 9.0	5.0 9.0	mA mA
		5455		9.0	16	mA
SMALL SI	GNAL CHARACTERISTICS			9.0	16	mA
SMALL SI 9fs	GNAL CHARACTERISTICS Forward Transfer Conductance*	V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz 5457 5458 5459	1000 1500 2000	9.0	5000 5500 6000	μmhos μmhos
9fs		V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz 5457 5458	1000 1500	10	5000 5500	μmhos μmhos μmhos
gfs gos	Forward Transfer Conductance*	V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz 5457 5458 5459	1000 1500		5000 5500 6000	μmho: μmho: μmho:
	Forward Transfer Conductance* Output Conductance*	$V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}$ 5457 5458 5459 $V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}$	1000 1500	10	5000 5500 6000 50	μmhos μmhos μmhos μmhos

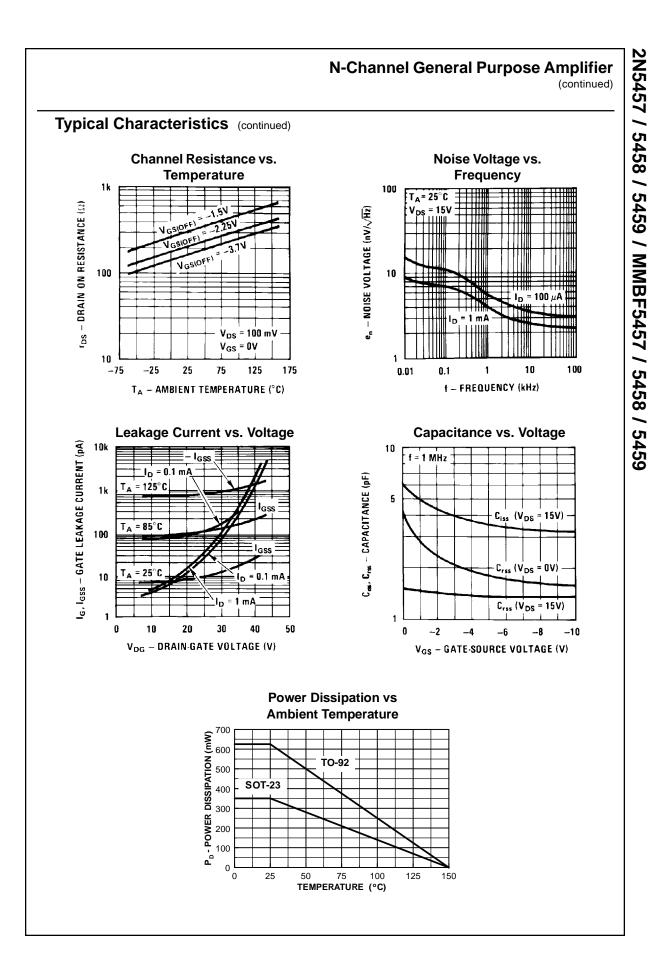




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